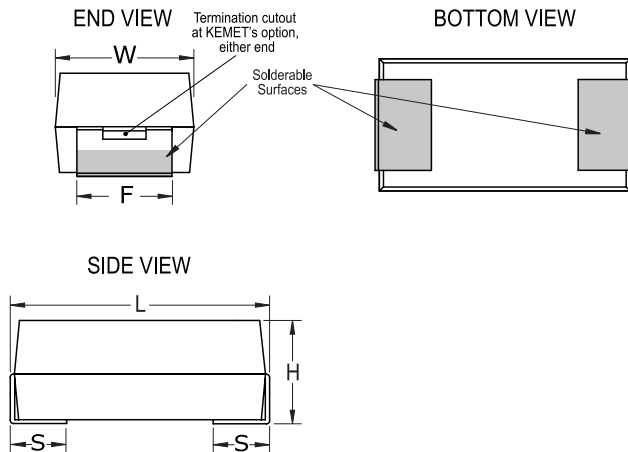


T493D335K050BH6320

Aliases (DLA Drawing 07016-167KBHB)

T493 HRA, Tantalum, MnO₂ Tantalum, HRA, 3.3 uF, 10%, 50 VDC, SMD, MnO₂, Molded, DLA Drawing, B (0.1%/1000 Hrs), 800 mOhms, 7343, 3.1 mm, 1.3 mm



Click [here](#) for the 3D model.

General Information

Series	T493 HRA
Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, MnO ₂ , Molded, DLA Drawing
RoHS	No
Prop 65	WARNING: Cancer and reproductive harm - https://www.p65warnings.ca.gov/
SCIP Number	1dd2e1b8-26dd-4d52-927c-6f9d519011aa
Termination	Tin Lead (SnPb)
AEC-Q200	No
Typical Component Weight	412.33 mg

Specifications

Capacitance	3.3 uF
Tolerance	10%
Voltage DC	50 VDC (85C), 33.5 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	0.8 Ohms (100kHz 25C)
Ripple Current	433 mA (rms, 100kHz 25C)
Leakage Current	1.7 uA (5min 25°C)
Testing and Reliability	10 Cycles Surge Current Testing At -55C And +85C After Weibull

Dimensions

L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	2.8mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

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